

# International **IR** Rectifier

**30WQ03F**  
**30WQ04F**

SCHOTTKY RECTIFIER

3.3 Amp

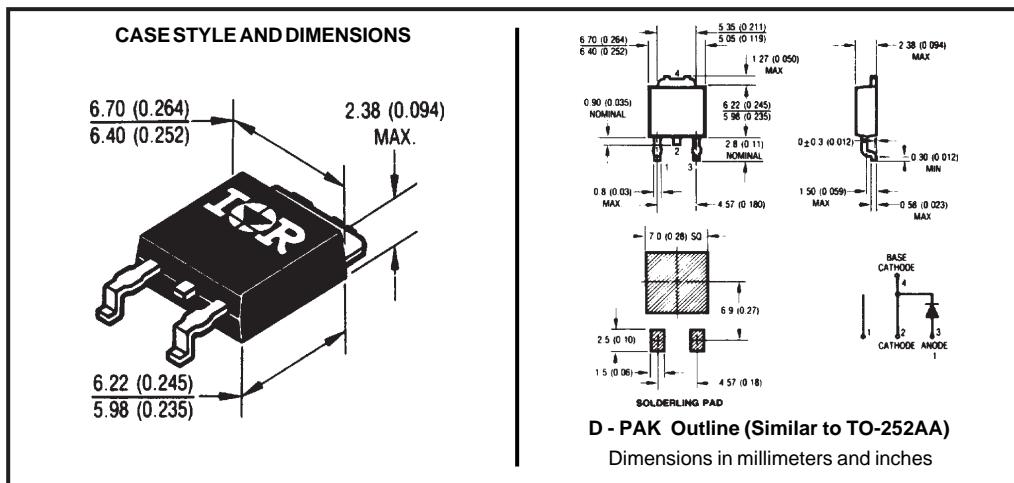
### Major Ratings and Characteristics

Characteristics	30WQ..F	Units
$I_{F(AV)}$ Rectangular waveform	3.3	A
$V_{RRM}$	30/40	V
$I_{FSM}$ @ $t_p = 5\ \mu s$ sine	470	A
$V_F$ @ $3\ A_{pk}, T_J = 25^\circ C$	0.62	V
$T_J$ range	-40 to 125	°C

### Description/Features

The 30WQ..F surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



30WQ03F, 30WQ04F

PD-2.301 rev. A 12/97

International  
 Rectifier

### Voltage Ratings

Part number	30WQ03F	30WQ04F
$V_R$ Max. DC Reverse Voltage (V)		
$V_{RWM}$ Max. Working PeakReverse Voltage (V)	30	40

### Absolute Maximum Ratings

Parameters	30WQ..F	Units	Conditions
$I_{F(AV)}$ Max.AverageForwardCurrent * See Fig. 5	3.3	A	50%duty cycle @ $T_J = 105^\circ\text{C}$ , rectangularwaveform
$I_{FSM}$ Max.PeakOneCycleNon-Repetitive Surge Current * See Fig. 7	470	A	5μs Sine or 3μs Rect. pulse
	40		10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated $V_{RRM}$ applied

### Electrical Specifications

Parameters	30WQ..F	Units	Conditions		
$V_{FM}$ Max. Forward Voltage Drop * See Fig. 1 (1)	0.62	V	@ 3A	$T_J = 25^\circ\text{C}$	
	0.88	V	@ 6A		
	0.56	V	@ 3A	$T_J = 125^\circ\text{C}$	
	0.69	V	@ 6A		
$I_{RM}$ Max. Reverse Leakage Current * See Fig. 2 (1)	2	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$	
	12	mA	$T_J = 125^\circ\text{C}$		
$C_T$ Typical Junction Capacitance	110	pF	$V_R = 5V_{DC}$ , (test signal range 100Khz to 1Mhz) $25^\circ\text{C}$		
$L_S$ Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body		
$dv/dt$ Max. Voltage Rate of Change (Rated $V_R$ )	10,000	V/ μs			

(1) Pulse Width &lt; 300μs, Duty Cycle &lt; 2%

### Thermal-Mechanical Specifications

Parameters	30WQ..F	Units	Conditions
$T_J$ Max.JunctionTemperatureRange	-40to125	°C	
$T_{stg}$ Max.StorageTemperatureRange	-40to125	°C	
$R_{thJC}$ Max.ThermalResistanceJunction toCase	6.0	°C/W	DCoperation * See Fig. 4
wt ApproximateWeight	0.3(0.01)	g(oz.)	
Case Style	D - PAK		Similar to TO-252AA

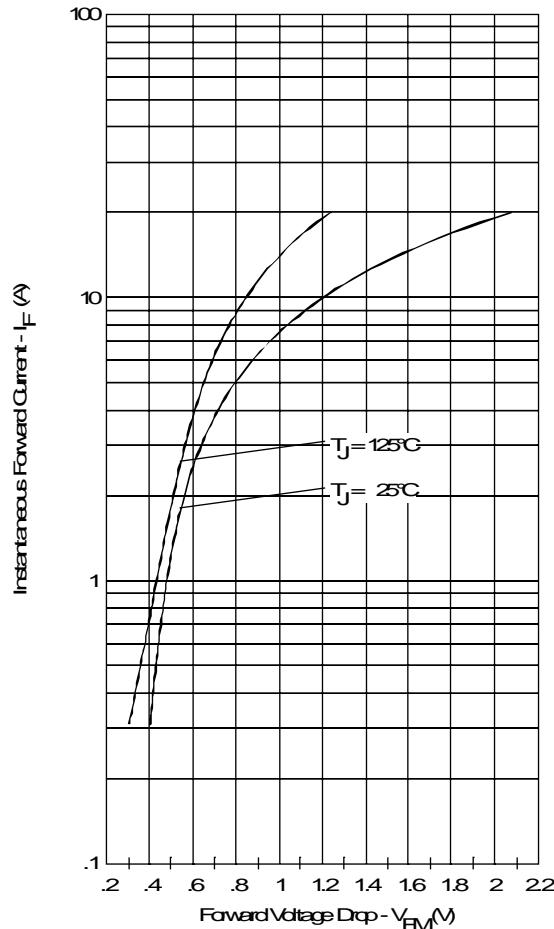


Fig. 1-Maximum Forward Voltage Drop Characteristics

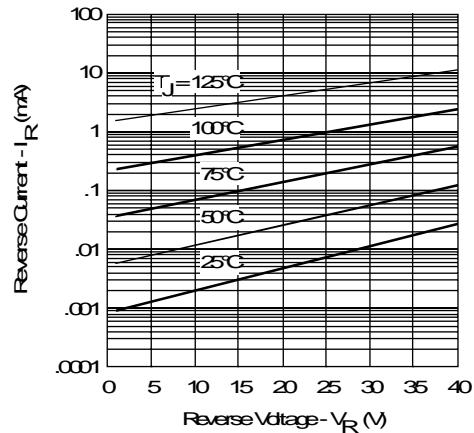


Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

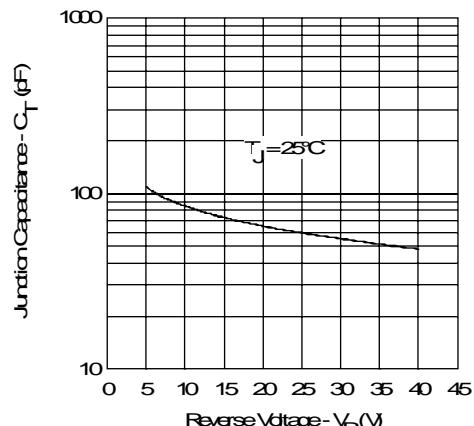


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

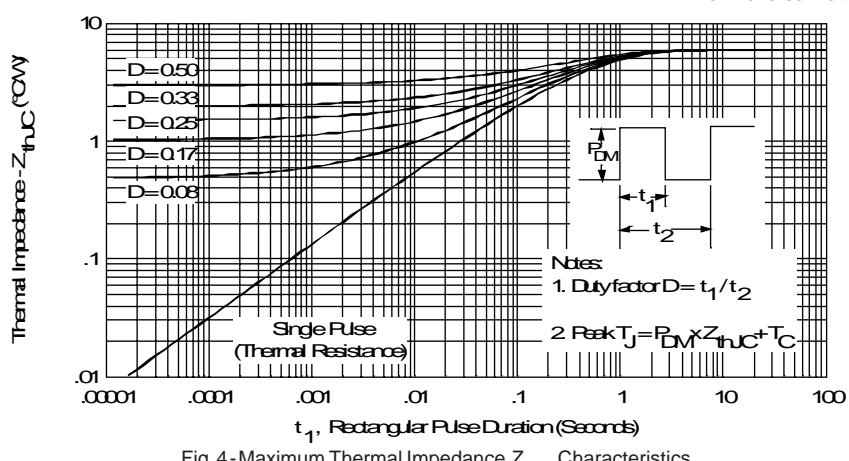


Fig. 4-Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

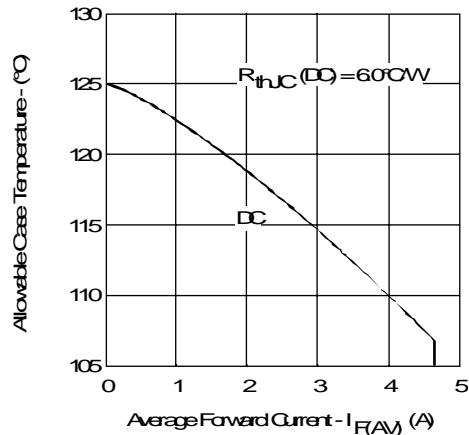


Fig.5-Maximum Allowable Case Temperature Vs. Average Forward Current

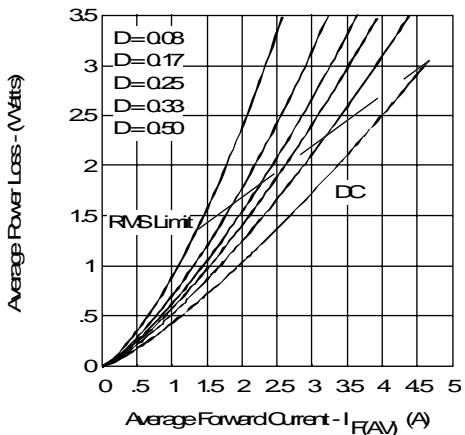


Fig.6-Forward Power Loss Characteristics

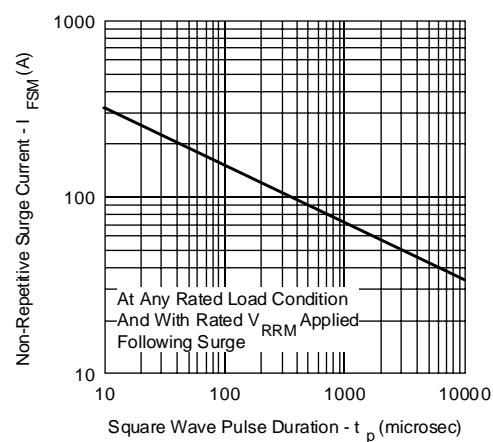


Fig.7-Maximum Non-Repetitive Surge Current